Investigations & Properties of Parametric X-Ray Radiation

Исследования & свойства параметрического рентгеновского излучения

A.V. Shchagin, Kharkov Institute of Physics and Technology, Kharkov 61108, Ukraine <u>shchagin@kipt.kharkov.ua</u>

XL Winter School PINP, S. Petersburg, Russia, February 2006 21 year of experimental discovery of PXR Tomsk 1985

• First theoretical predictions

- Ya. B. Fainberg, N.A. Khizhnyak JETP 1957
- M.L. Ter-Mikaelian, book, 1969 X-rays
- V.G. Baryshevsky, I.D. Feranchuk; G.M. Garibian, C. Yang - Dynamical theory -1970

Some reviews about PXR properties and investigations

- M.L. Ter-Mikaelian, *Electromagnetic radiation processes in periodic media at high energies*, Uspekhi Fizicheskikh Nauk, 171, 597-624 (2001) [in Russian]. Physics-Uspekhi 44, 571-596 (2001) [in English].
- 2. A.V. Shchagin, X.K. Maruyama, *Parametric X-rays,* in: Acceleratorbased atomic physics technique and applications, eds. S.M. Shafroth, J.C. Austin (AIP Press, New York, 1997) pp. 279-307.
- 3. Rullhusen, A. Artru, P. Dhez, *Novel radiation sources using relativistic electrons,* World Scientific Publishers, Singapore, 1998.
- A.V. Shchagin, *Investigations and properties of PXR*, in: Electronphoton interactions in dense media, ed. by H. Wiedemann, NATO Science Series, II Mathematics, Physics and Chemistry, Vol. 49, Kluwer Academic Publishers, Dordrecht/Boston/London, 2002, pp. 133-151.

Схема Гюйгенса для излучения Вавилова-Черенкова



Рис. 1.1. Схема Гюйгенса для излучения Вавилова-Черенкова. Заряженная частица движется в однородной среде со скоростью расположенных всреде, со скоространяются из точек Р1-Р3, произвольно расположенных вдоль траектории частицы. Излучение Вавилова-Черенкова распространяется вдоль вектора

A.V. Shchagin, S.Petersburg, February 2006

The Huygens construction for generation of PXR



A.V. Shchagin, S.Petersburg, February 2006



A.V. Shchagin, S.Petersburg, February 2006

Common schemes for generation of PXR



Измерение дифференциальных свойств РХR.

Схема экспериментальной установки с энергией пучка электронов 15.7-25.7 МэВ.



A.V. Shchagin, S.Petersburg, February 2006

Эффективная площадь регистрации Si(Li) детектора рентгеновского излучения со свинцовой диафрагмой диаметром 3.7 мм



A.V. Shchagin, S.Petersburg, February 2006

Спектр рентгеновского излучения измеренный при 142.9 мрад и энергии электронов 25.0 МэВ из монокристалла Si

Shchagin A.V., Pristupa V.I., Khizhnyak N.A. Phys. Lett. A 148, 485-488 (1990).



A.V. Shchagin, S.Petersburg, February 2006

10

Спектры рентгеновского излучения измеренные при различных углах поворота мишени и энергии электронов 25.0 МэВ.



A.V. Shchagin, S.Petersburg, February 2006

Энергии спектральных пиков в зависимости от угла поворота кристалла



A.V. Shchagin, S.Petersburg, February 2006

Эффект ряда для РХR. Структура векторов обратной решетки монокристалла кремния в плоскости перпендикулярной вектору обратной решетки с индексами Миллера. (-220)



A.V. Shchagin, S.Petersburg, February 2006

Абсолютный дифференциальный выход числа квантов ПРИ в спектральном пике вблизи рефлекса

Shchagin A.V., Khizhnyak N.A. Nucl. Instr. and Meth B 119, 115-122 (1996)



A.V. Shchagin, S.Petersburg, February 2006

14

Абсолютный дифференциальный выход числа квантов ПРИ в спектральном пике вдали от рефлекса



A.V. Shchagin, S.Petersburg, February 2006

Угловое размер рефлекса ПРИ в зависимости от энергии электронов.



A.V. Shchagin, S.Petersburg, February 2006

16

Дифференциальный выход ПРИ в левом и правом максимумах в зависимости от энергии электронов



A.V. Shchagin, S.Petersburg, February 2006

17

Angular distribution of the PXR yield at 90 degree. Fiorito R.B. et al, Phys. Rev. E 51, R2759-R2762 (1995).



A.V. Shchagin, S.Petersburg, February 2006

The setup for calibration of X-ray space telescopes at distance 518 m



X-ray flux intensity at distance 518 meters



Fig. 2. X-ray flux intensity at the telescope aperture in units of quanta number per cm^2 per second as a function of quanta energy for incident electron energies of 60, 120 and 180 MeV.

X-ray locator based on the PXR for control of nuclear materials U, Pu



The number of K characteristic quanta arriving in 1 sec at the 100 cm2 detector from the U target of area 1 cm2.



A.V. Shchagin, S.Petersburg, February 2006

Production of PXR in a grain of a polycrystal. pA.V.

A.V. Shchagin, preprint <u>http://arXiv.org/abs/physics/0105071 (2001</u>); Вопросы атомной науки и техники. Серия «Плазменная электроника и новые методы ускорения» №4, 76-79 (2004).



The relativistic particle beam passes through the radiator R and generates radiation in a forward direction (RFD). The RFD is going along the particle velocity vector \vec{V} and passes through the polycrystalline foil P. One of randomly aligned grains of the polycrystal with the crystallographic planes and corresponding reciprocal vector \vec{g} is shown in the foil. The spectrometric X-ray detector D is installed at observation angle θ relative to particle velocity vector. The observation direction is shown by the unit vector $\vec{\Omega}$. The detector can register RFD diffracted by polycrystal at Bragg energies

Experiment on PXR from textured polycrystal at 150 MeV REFER ring at Hiroshima University



A.V. Shchagin, S.Petersburg, February 2006

X-ray spectra from 10mkm thick Mo textured polycrystal. Y. Takabayashi, I. Endo, K. Weda, C. Moriyoshi, A.V. Shchagin,, NIMB B 243, 453-456 (2006).



A.V. Shchagin, S.Petersburg, February 2006

25

The yield and the spectral peak energy of PXR from textured Mo polycrystal

NIMB B 243, 453-456 (2006).



A.V. Shchagin, S.Petersburg, February 2006

Intense PXR from textured polycrystal

S. Nawang¹, I. Endo¹, M. linuma¹, A. Kohara¹, H. Kuroiwa², C. Moriyoshi³, T. Ohnishi^a,

A. V. Schagin⁴, S. Strokov¹, Y. Takabayashi², T. Takahashi¹, K. Ueda¹ 1) Graduated School of Advanced Sciences of Matter, Hiroshima University, Japan

2) Venture Business Laboratory, Hiroshima University, Japan

3) Graduated School of Science, Hiroshima University, Japan 4) Kharkov Institute of Physics and Technology, Ukraine



A.V. Shchagin, S.Petersburg, February 2006



PXR may be extracted from long crystal. Positive particle moves in channeling regime. Multiple scattering is reduced

Fig



Production of focused PXR by particles channeling in a bent crystalline plate



Production of focused PXR by particles channeling in a bent crystalline plate. The side and front views are shown in Figs. 1a and 1b, respectively. The particle beam is indicated by arrows p+. The particles are channeling along the crystallographic planes denoted by the reciprocal lattice vector g. The single-crystal plate is cylindrical in shape with a radius of curvature around the axis R. The wavy lines with arrows show the direction of radiation propagation at the maxima of the PXR reflections. The PXR reflections from the crystallographic planes denoted by the reciprocal lattice vector g1 are focused at points F1 and F2 on the axis f. The PXR focused at points F1 and F2 is linearly polarized practically in the plane of Fig. 1b. The PXR reflections from the crystallographic planes denoted by the reciprocal lattice vector g2 are going in opposite directions and form virtual images of points F1 and F2.

The Huygens construction for focusing the PXR wave train A.V. Shchagin, JETP Letters, 80, 535-540 (2004).



Fig

Properties of CXR and focused PXR induced by 70 and 450 GeV protons. Si crystal size is 50*0.3 mm. X-ray detector square is 1 cm²

Table

		012 PD - 01		535 (000)	D D D D D D D D D D
Radiation		CXR S1	P.X.R(400)	PXR(800)	PXR(12.00)
Polarization		No	Linear	Linear	Linear
$ar{E}$, keV		1.74	6.46	12.91	19.37
(Δ Ξ /Ξ) _{nar}			3.84 · 10 ⁻⁹	1.92.10 ⁻⁹	1.28·10 ⁻⁹
(Δ B /B) _D			2.10-3	2·10 ⁻³	2.10-3
T _e in Si, µn		13.3	37	270	865
Protons 70 GeV	Y_{eff}^{-1}	-	1.42.10 ⁻²	1.36.10 ⁻²	1.35.10 ⁻²
	∆F,mm	-	142	136	135
	$I, \frac{quanta}{cm^2 \cdot p^+}$	1.65.10 ⁻⁷	9 <i>5</i> 6·10 ⁻⁸	1.86.10	1.55.10 ⁻⁹
Protons 450 GeV	Y_eff	-	524.10-3	3.18-10 ⁻³	2.63.10-3
	∆F,mm	-	52.4	31.8	26.3
	$I, \frac{quanta}{cn^2 \cdot p^+}$	194.10-7	6.90·10 ⁻⁷	3.32·10 ⁻⁷	398·10 ^{-\$}

Diffraction and focusing of backward PXR



The backward-going PXR is generated on the crystallographic planes denoted by the reciprocal lattice vector g3. It is shown by a horizontal wavy line with the arrow. Then it is diffracted on the crystallographic planes denoted by the reciprocal lattice vector g2 and is focused at the axis f. The angular path before the diffraction is $g_{eff}^{-2}/2$ Shchagin, NATO ARW, Armenia 1994

A.V. Shchagin, S.Petersburg, February 2006

Properties of diffracted and focused backward PXR induced by 70 and 450 GeV protons

Table

Radiation	Ε,	Diffraction	Protons 70 GeV	Protons 450 GeV
from \vec{g}_3	keV	from \vec{g}_2		
			J_quanta	J_quanta
			$i cm^2 \cdot p^+$	$i cm^2 \cdot p^+$
PXR(440)	6.46	(040)	3.30 -10 ⁻¹⁵	3.36 10-8
PXR(880)	12.91	(080)	3.86 ·10 ⁻¹⁰	3.56-10-8
PXR(12120)	19.37	(0120)	6.38 10 ⁻¹¹	2.78 10-8

Extraction of channeling radiation from a long crystal



- Positrons or other positive particles are channeling in a perfect crystal along the crystallographic planes denoted by the reciprocal lattice vector g. They emit channeling radiation (ChR) going along the particle trajectory. A part of the ChR of Bragg frequency is diffracted to the Bragg direction relative to the crystallographic planes denoted by the reciprocal lattice vector g1. The Bragg direction is shown by a dotted line. The angular distribution of ordinary PXR reflection is shown schematically around the Bragg direction. The angular distribution of diffracted and extracted DChR is shown along the Bragg direction.
- The diffraction of channeling radiation was theoretically considered in: T. Ikeda, Y. Matsuda, H. Nitta, Y.H. Ohtsuki, Parametric X-ray radiation by relativistic channeled particles, Nucl. Instr. and Meth. B 115, 380-383 (1996).

Focusing of channeling radiation



Focusing of channeling radiation. Positrons or other positive particles are channeling along the bent crystal in the crystallographic planes denoted by the reciprocal lattice vector g. They emit channeling radiation along of the particles trajectory. The diffracted at crystallographic planes denoted by reciprocal lattice vector g1 and extracted part of the channeling radiation (DChR) is focused at point F3. The ordinary PXR reflection is focused at points F1 and F2 just as in Fig. 1.

The PXR from a crystal undulator



Generation of PXR reflections from the crystal undulator. The channeling particle emits crystal undulator radiation (CUR) in the forward direction. Besides, it emits PXR reflections in Bragg directions relative to different crystallographic planes of the crystal undulator. Only two sets of crystallographic planes denoted by the reciprocal lattice vectors g1 and g2 as well as the related Bragg directions and PXR reflections are shown in the figure.

Extraction of crystal undulator radiation



Extraction of undulator radiation from the crystalline undulator. The diffracted and extracted crystal undulator radiation (DCUR) is going along the Bragg direction. The PXR reflection is around the Bragg direction for the crystallographic planes denoted by the reciprocal lattice vector g1. The frequency of CUR should satisfy to Bragg condition for these crystallographic plane.

Focusing of crystal undulator radiation



Diffraction, extraction and focusing of crystal undulator radiation. Positrons or other positive particles are channeling along a cylindrically bent crystal undulator in the crystallographic planes denoted by the reciprocal lattice vector g. They emit the CUR along of particles trajectory The diffracted and extracted part of the crystal undulator radiation (DCUR) is focused at the point F3 at axis f. The ordinary PXR reflection is focused at points F1 and F2 just as in Fig. 1. The CUR frequency should satisfy to Bragg condition.

The focused PXR train will possess the periodical frequency and phase modulation with the period determined by the crystal undulator period.

Applications of PXR in experiments with long crystal

- 1. For high yield of PXR
- 2. For focusing of PXR
- 3. For proper alignment of the crystal undulator and for control and monitoring of the experiment
- 4. For focusing of channeling and undulator radiation
- 5. For generation of wavetrains with phase modulation

Thanks for Your Attention !